

High-accuracy EUV reflectometry at PTB



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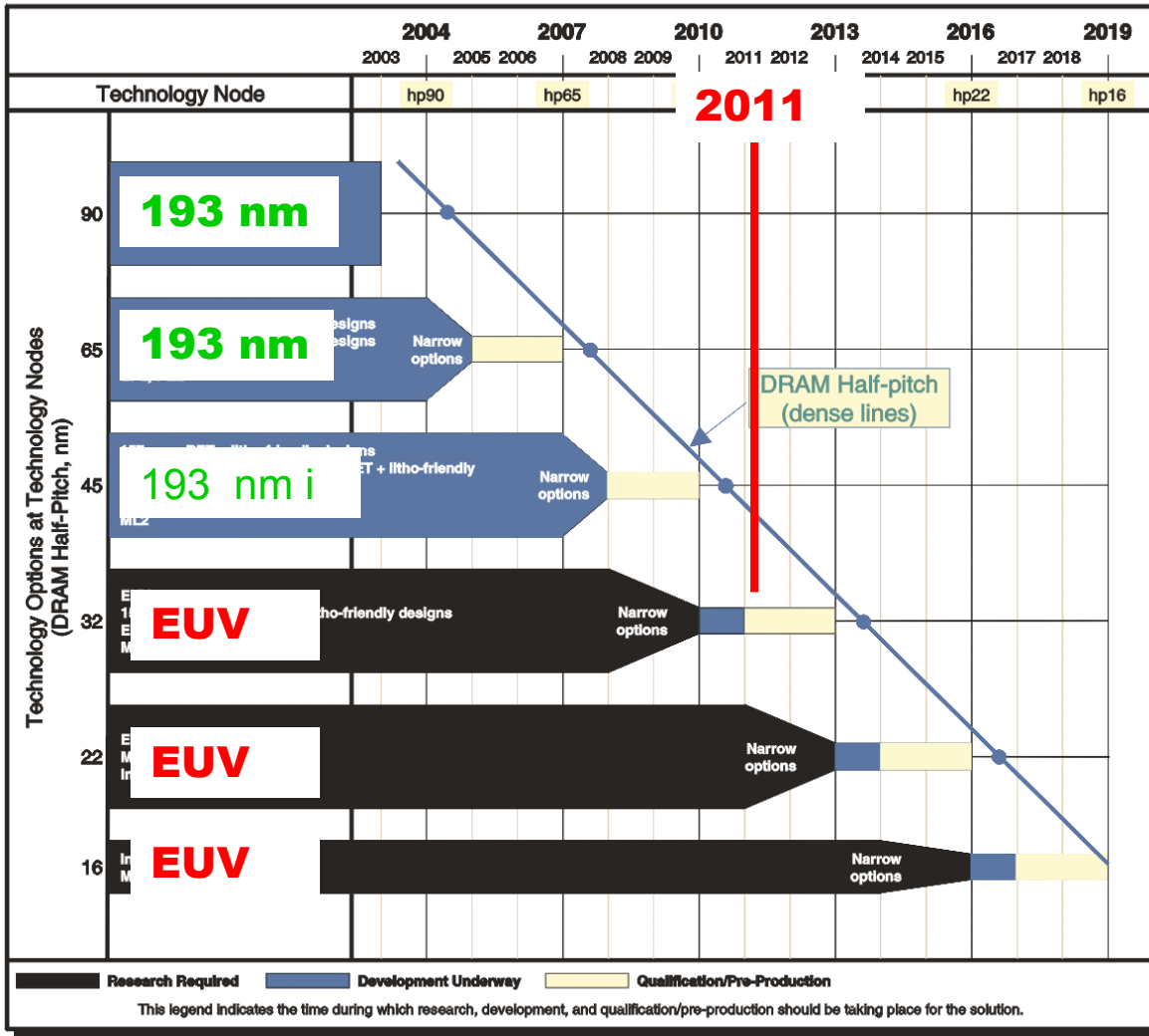
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Outline

- PTB laboratory at BESSY II
- Instrumentation
- Measurement examples, uncertainties
- Micro reflectometry facility
- Future developments

ITRS: Lithographie - Roadmap

Figure 53 Lithography Exposure Tool Potential Solutions

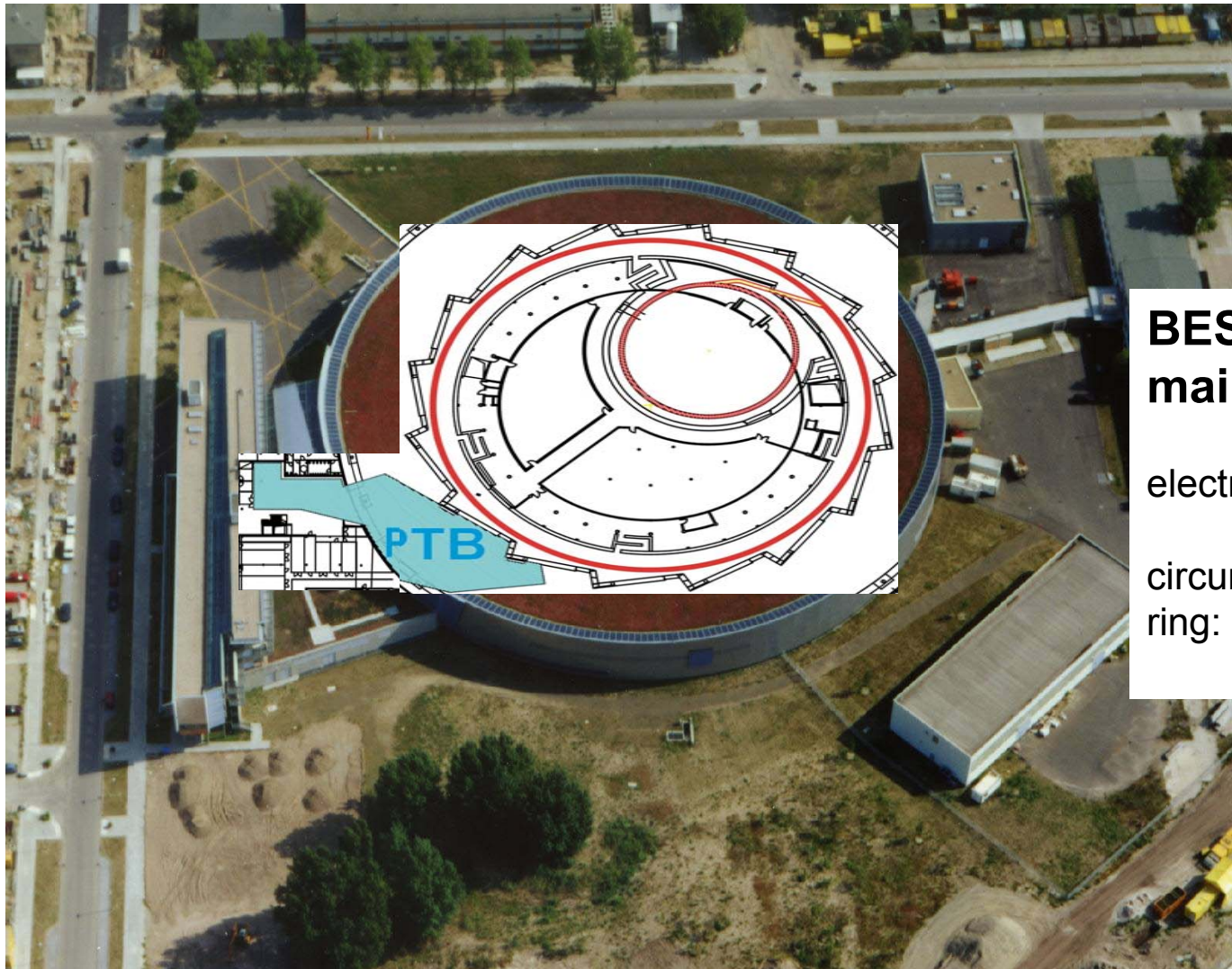


wavelength:

excimer-Laser

13.5 nm Extreme UV

PTB Radiometry Laboratory at BESSY II

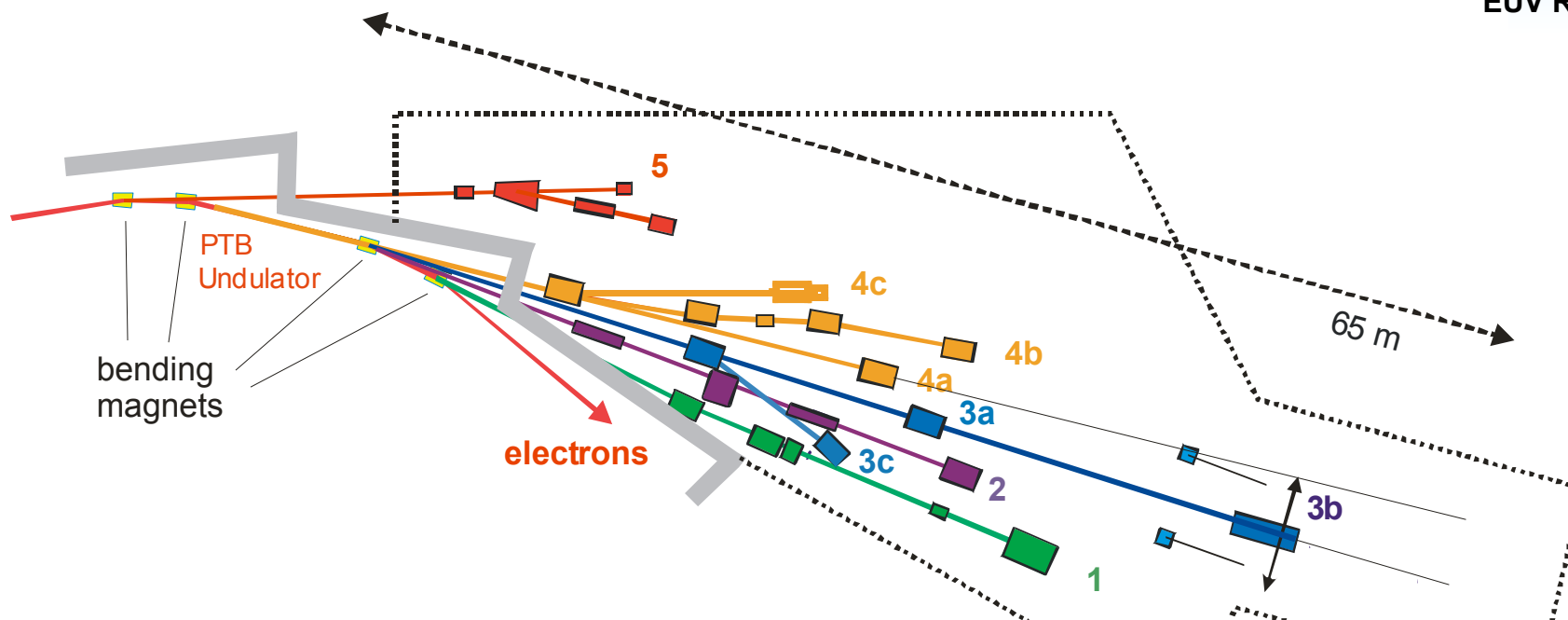


BESSY II main parameters

electron energy 1.7 GeV

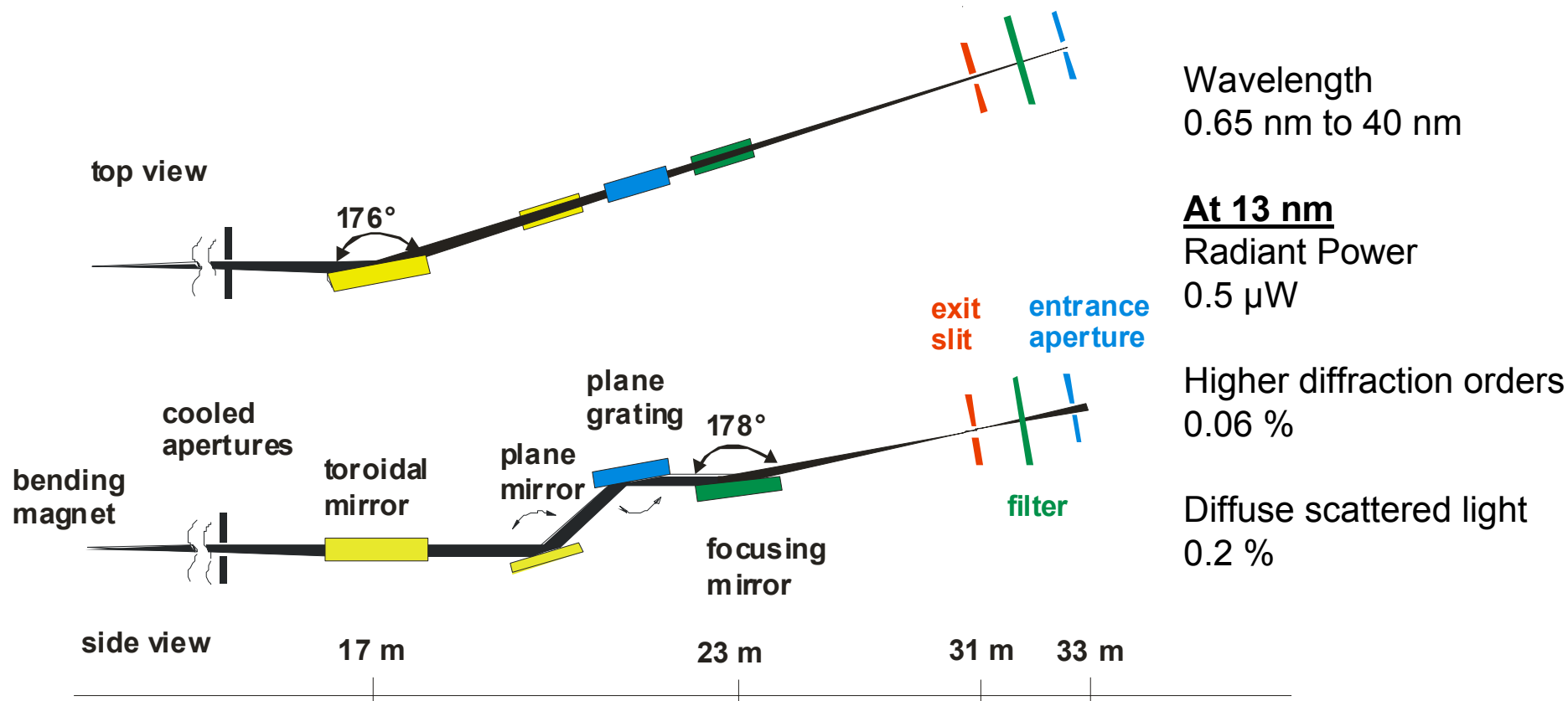
circumference of storage
ring: 240 m

PTB Radiometry Laboratory



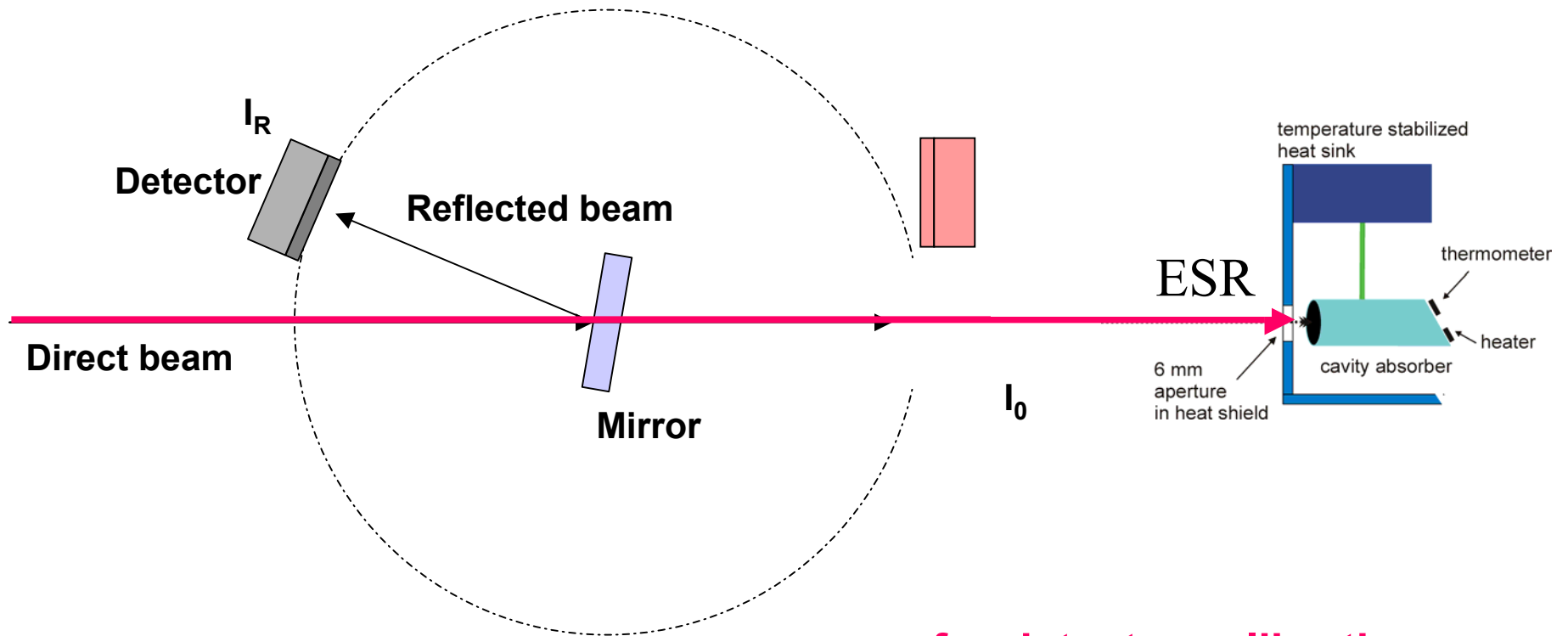
1	plane grating monochromator 30 eV to 1800 eV	4a	undispersed undulator radiation
2	four crystal monochromator 1.75 keV to 10 keV	4b	plane grating monochromator at undulator 20 eV to 1900 eV
3a	undispersed bending magnet radiation	4c	deflected undispersed undulator radiation
3b	normal incidence monochromator radiation source calibration 3 eV to 35 eV	5	normal incidence monochromator detector calibration 3 eV to 35 eV
3c	deflected undispersed bending magnet radiation		

Soft X-ray radiometry beamline



Optical scheme of the soft X-ray radiometry beamline

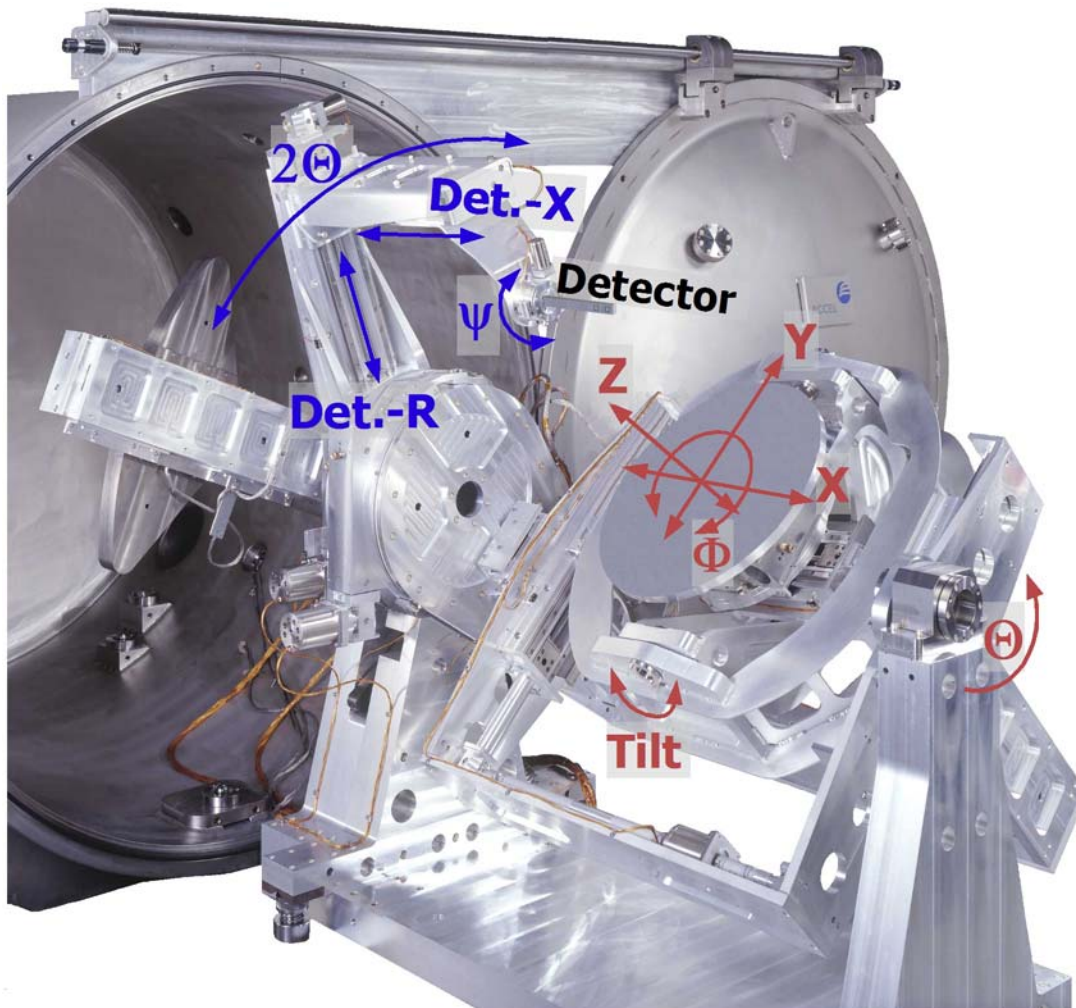
Reflectometry



$$R = \frac{I_R / I_{\text{Ring}}}{I_0 / I_{\text{Ring}}}$$

for detector calibration
see poster this afternoon

PTB Reflectometer



Axis	Range
Θ	-30° to 95°
Tilt	-10° to 10°
Φ	0° to 360°
X	-90 mm to 90 mm
Y	-10 mm to 300 mm
Z	-15 mm to 140 mm
Det. X	0 mm to 120 mm
Det. R	150 mm to 550 mm
Det. Ψ	0° to 180°
2θ	-5° to 190°

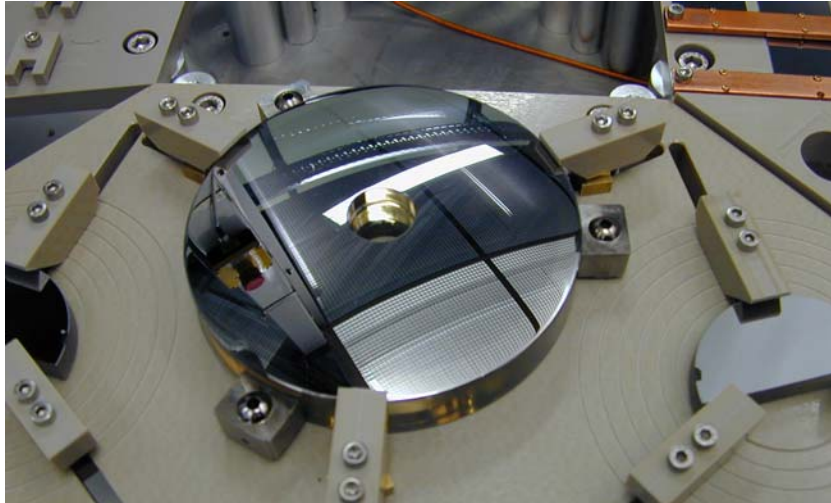
Accuracy: 10 μ m or 0.01°

Diameter: 2 m

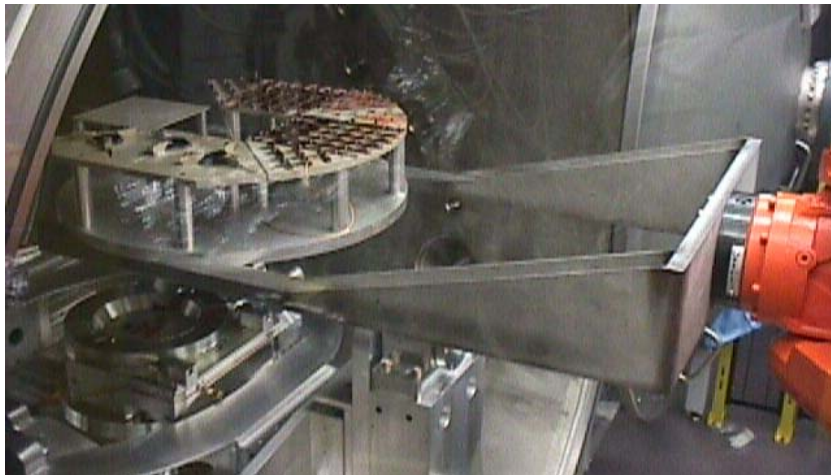
Length: 2.1 m

Weight: 3 t

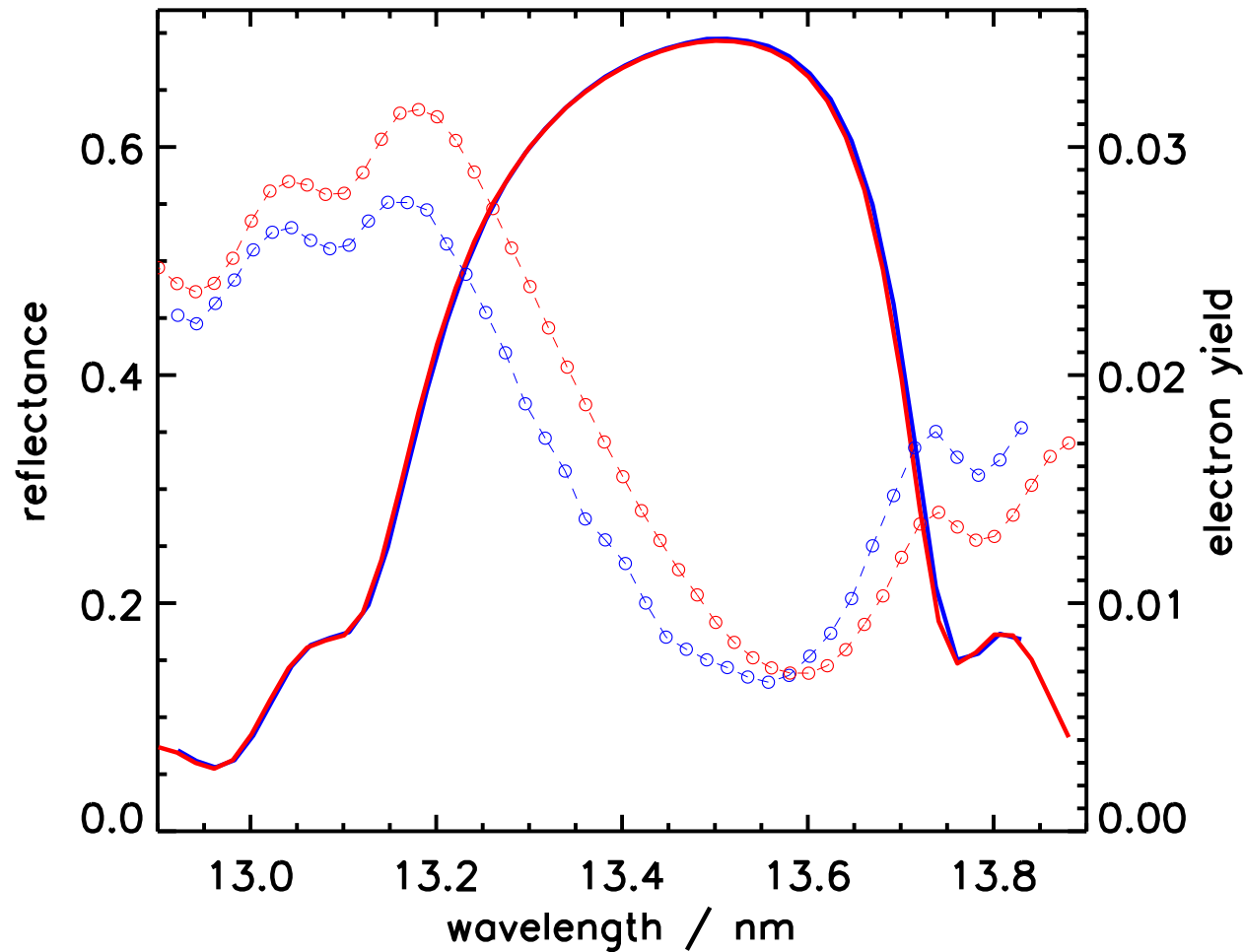
Sample holder



Sample mounting



Photocurrent and reflectance measurement

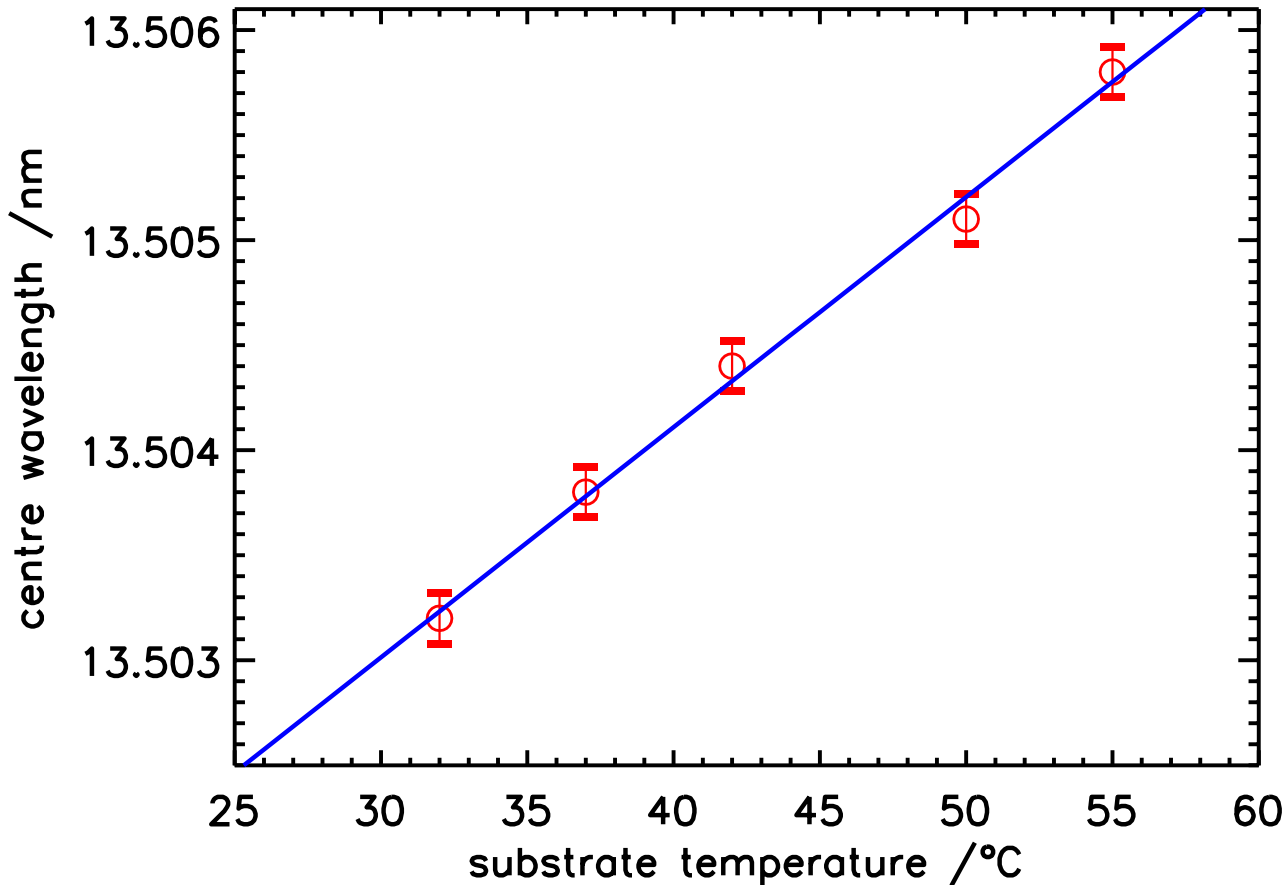


Reflectance of a mirror
measured in
March 2002
August 2004

spectral reflectance
- line
photocurrent
- circles

Repeatability of wavelength

measured shift of the centre wavelength as function of substrate temperature



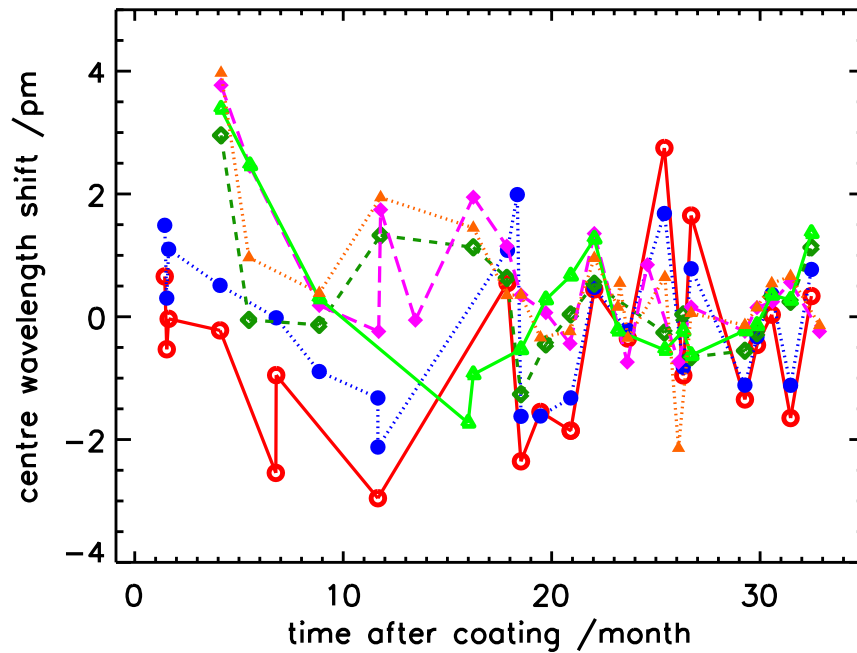
error bars:

signal statistics,
0.12 pm (2σ)

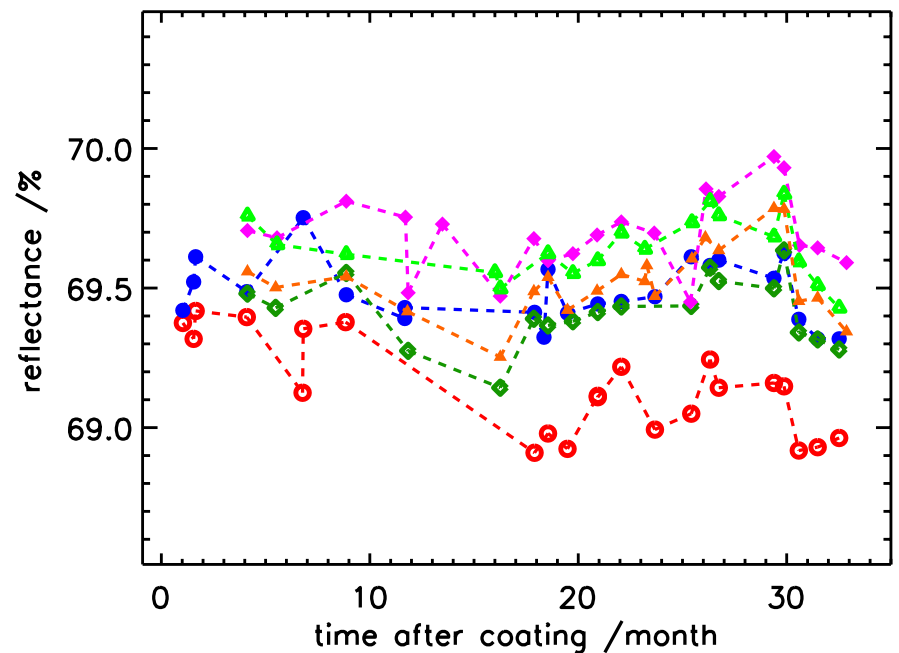
line:

linear fit with a thermal
expansion coefficient of
 $8.1(4)10^{-6} \text{ K}^{-1}$.

Long-term reproducibility



measured shift of centre wavelength of EUV mirrors after coating.



measured reflectance of EUV mirrors after coating.

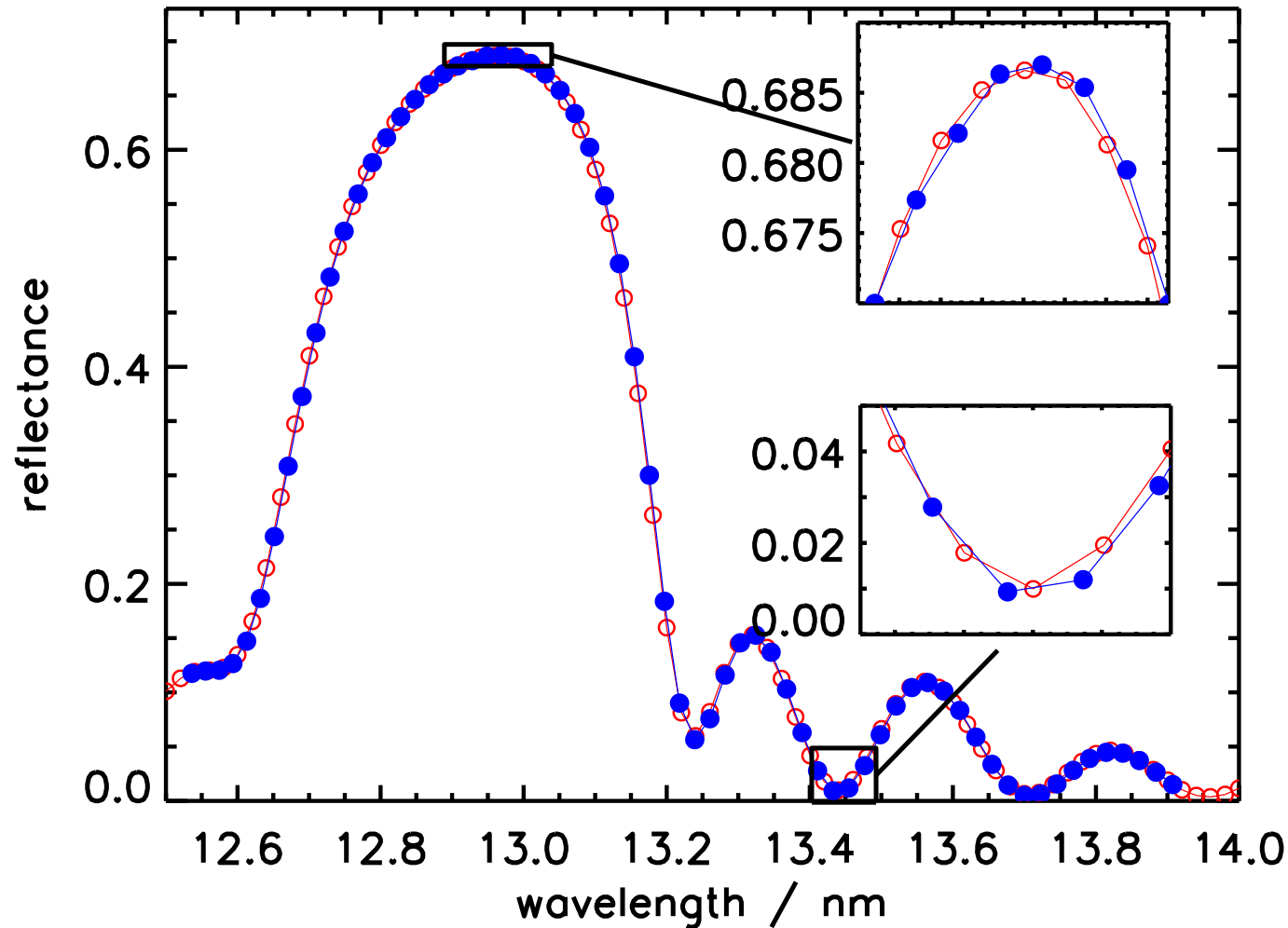
Compilation of uncertainties



EUV Radiometry

Peak reflectance	Uncertainty contribution u /%	Peak wavelength	Uncertainty contribution u /pm
Stability of normalised intensity	0.02	Repeatability of wavelength	0.06
Inhomogeneity of the detector	0.04	Reproducibility of wavelength (reference to Be K-edge)	1.1
Higher diffraction orders	0.02	Kr resonance wavelength	1.6
Diffuse scattered light	0.08		
Total uncertainty of peak reflectance	0.1	Total uncertainty of peak wavelength	2.0

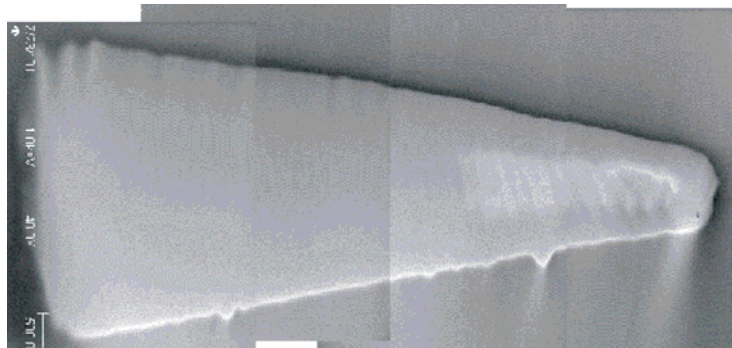
Comparison between CXRO and PTB



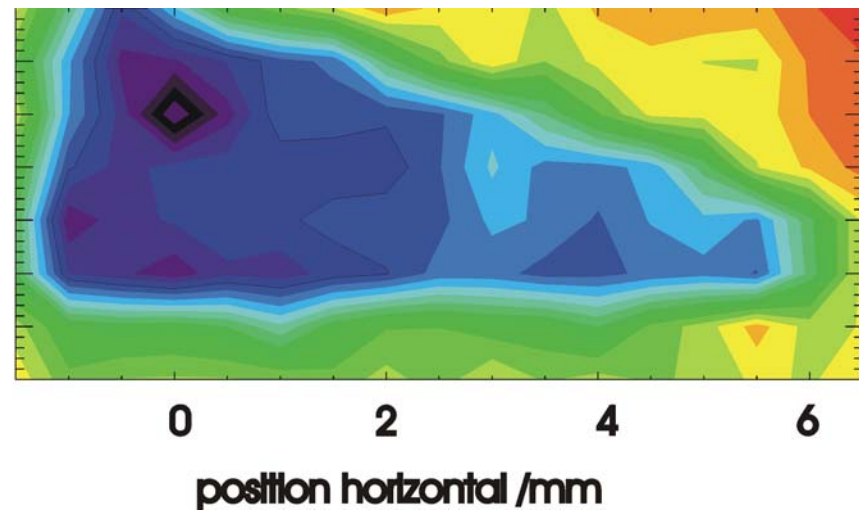
reflectance
at PTB (blue)
and CXRO (red)

Irradiation testing

carbon contamination by EUV irradiation



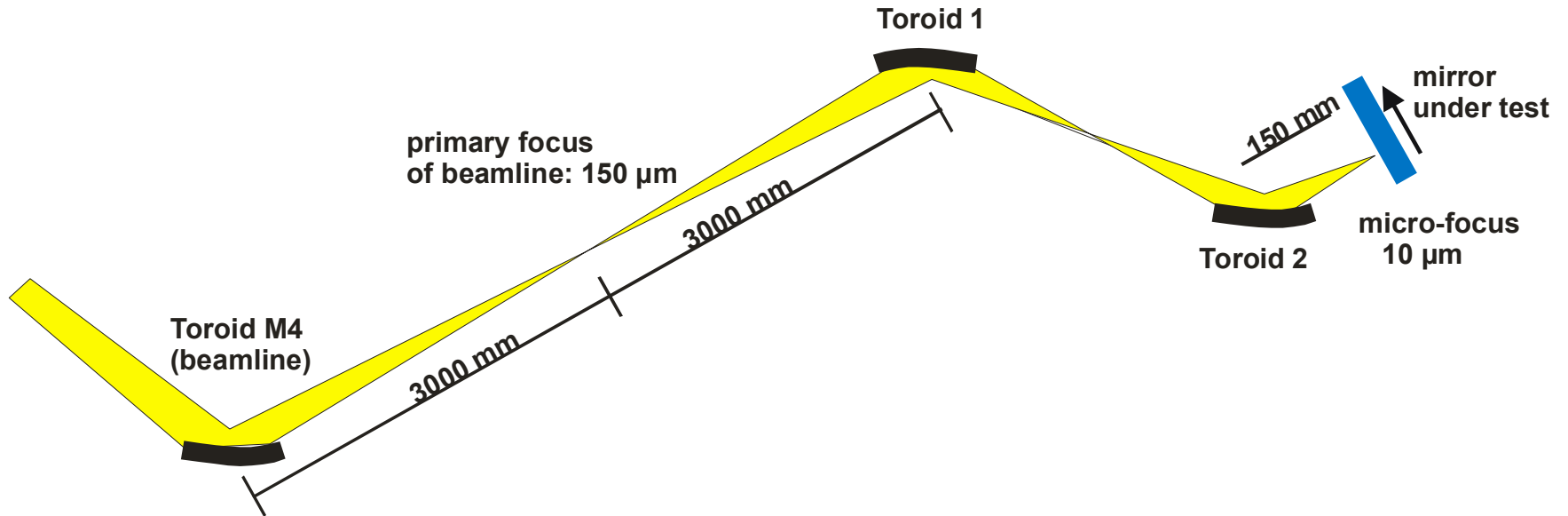
position vertical /mm



scanning electron microscope

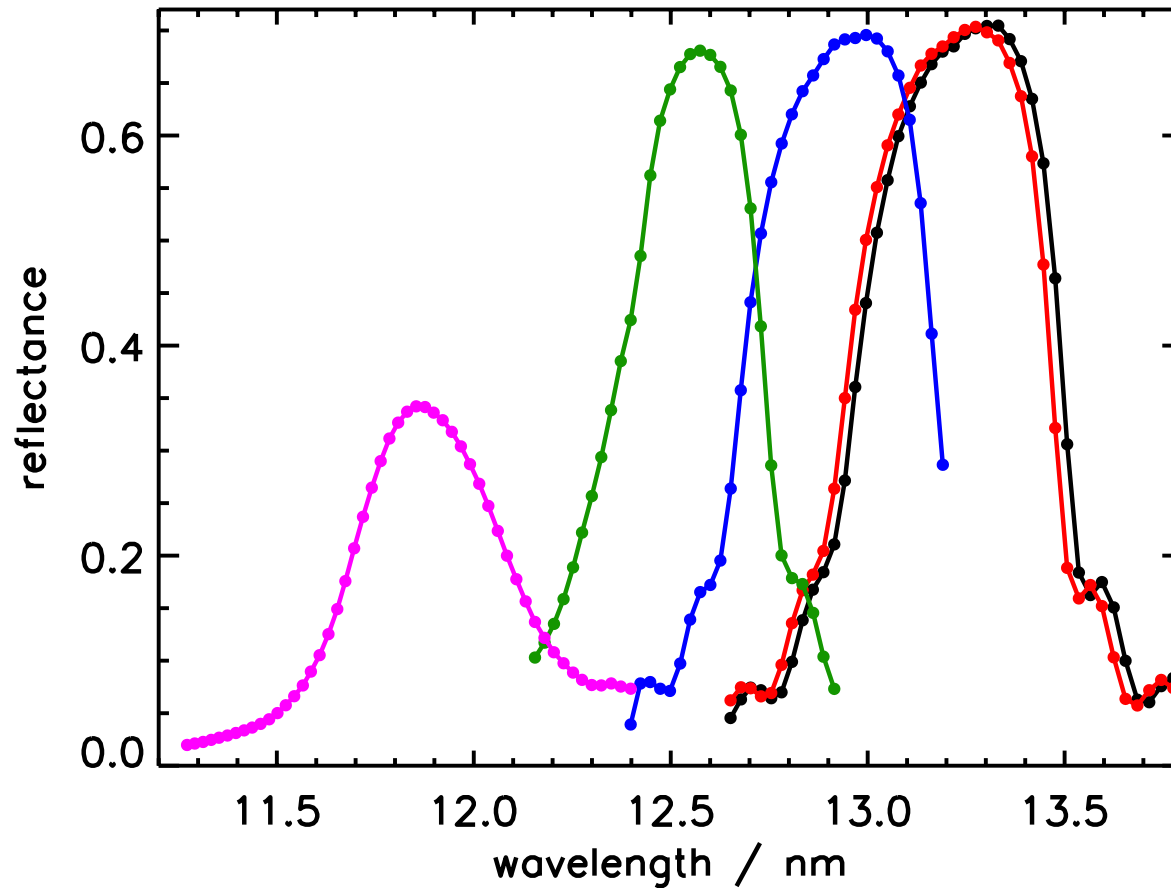
spot in reflectance scan

Micro reflectometry



At the undulator beamline of PTB, a refocusing unit with 10 μm focal spot is installed. Using a reflectometer for sample sizes up to 160 mm, micro-reflectometry with about 10 μm spatial resolution can be done at mirrors and masks.

Characterization of multilayer coating close to the substrate edge



Reflectance as function of wavelength

centre of the mirror (black).

and radii of

9.5 mm (red)

10.55 mm (blue),

10.7 mm (green), and

10.8 mm (magenta).

Customers of PTB for EUV radiometry



Major scientific cooperations:

partner

task

Carl Zeiss SMT AG

at-wavelength-metrology for EUV lithography

XTREME

EUV source characterization tools

AMTC

Charact. of EUVL masks

about 75% usage of available beam time, ~1000 mirrors /year

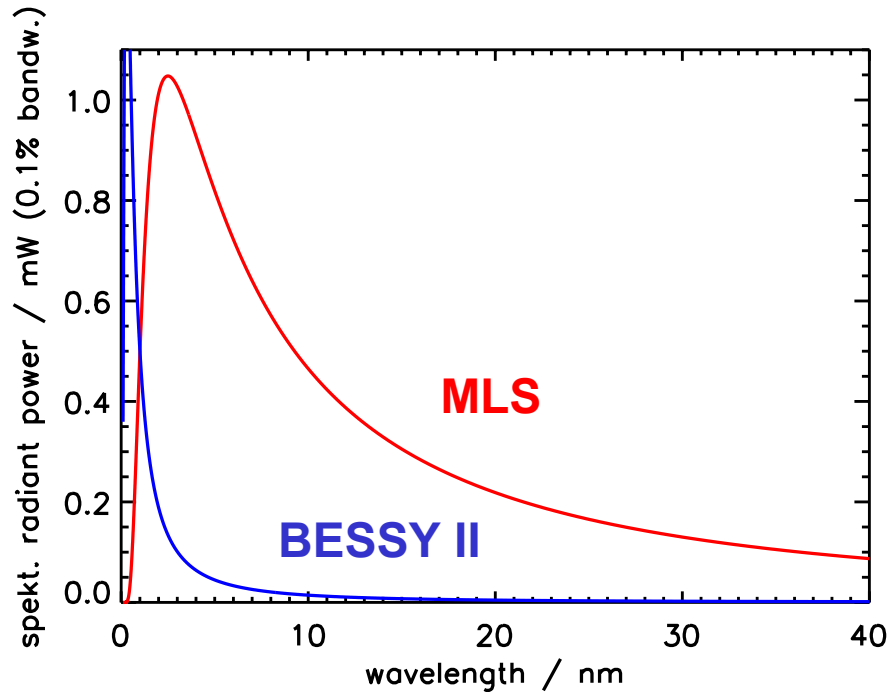
other research contracts with various partners from research and industry

Outlook: Metrology Light Source for EUV radiation



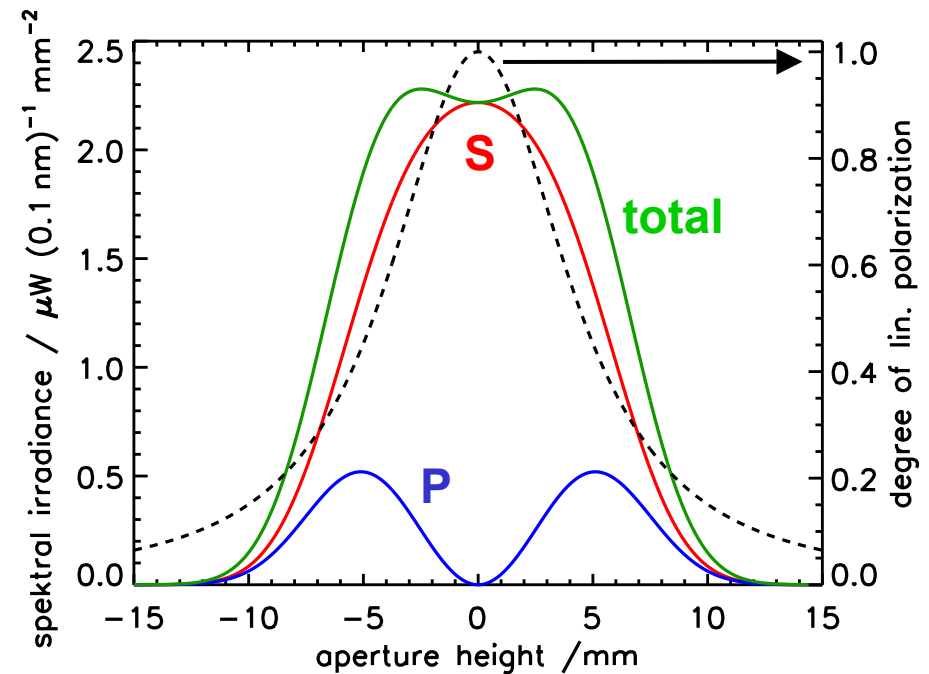
New Options

- high radiant power



100-times increase as compared to BESSY II

- variable polarization



usage of off-axis radiation at the MLS

Conclusion

- **EUVL development requires high-accuracy, high-volume reflectometry**
- **PTB serves the European industry at a dedicated beamline**
- **excellent long term reproducibility is achieved**
- **new options for micro reflectometry are available**
- **future use of the MLS will enable new applications**